

Description

The 74AHCT138 is an advanced high speed CMOS device that is designed to be pin compatible with 74LS low power Schottky types.

The device accepts a three bit binary weighted address on input pins A0, A1 and A2 and when enabled will produce one active low output with the remaining seven being high.

There are two active LOW enable inputs $\bar{E}1$ and $\bar{E}2$, and one active HIGH enable input E3. The disabled device state results in all outputs being high. The enable state occurs with $\bar{E}1$ and $\bar{E}2$ asserted low and E3 asserted high.

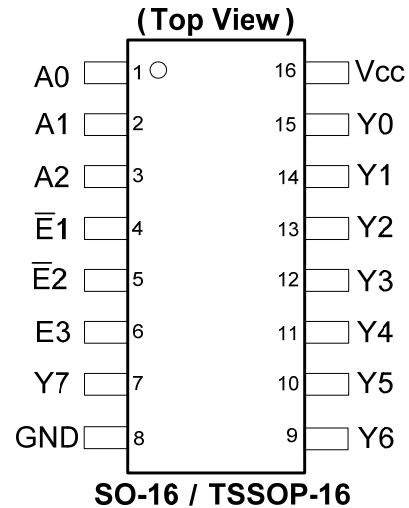
The multiple enable lines allow for the parallel expansion of decoders to create 4-to-16 line versions with no additional parts and 5-to-32 versions with the addition of a single inverter.

Features

- Supply Voltage Range from 4.5V to 5.5V
- Sinks or Sources 8mA at $V_{CC} = 4.5V$
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Inputs Accept up to 6.0V
- ESD Protection Tested per JESD 22
- Exceeds 200-V Machine Model (A115-A)
- Exceeds 2000-V Human Body Model (A114-A)
- Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



Applications

- Memory chip select decoding
- Demultiplexing
- Single line peripheral control
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed

[Click here for ordering information, located at the end of datasheet](#)

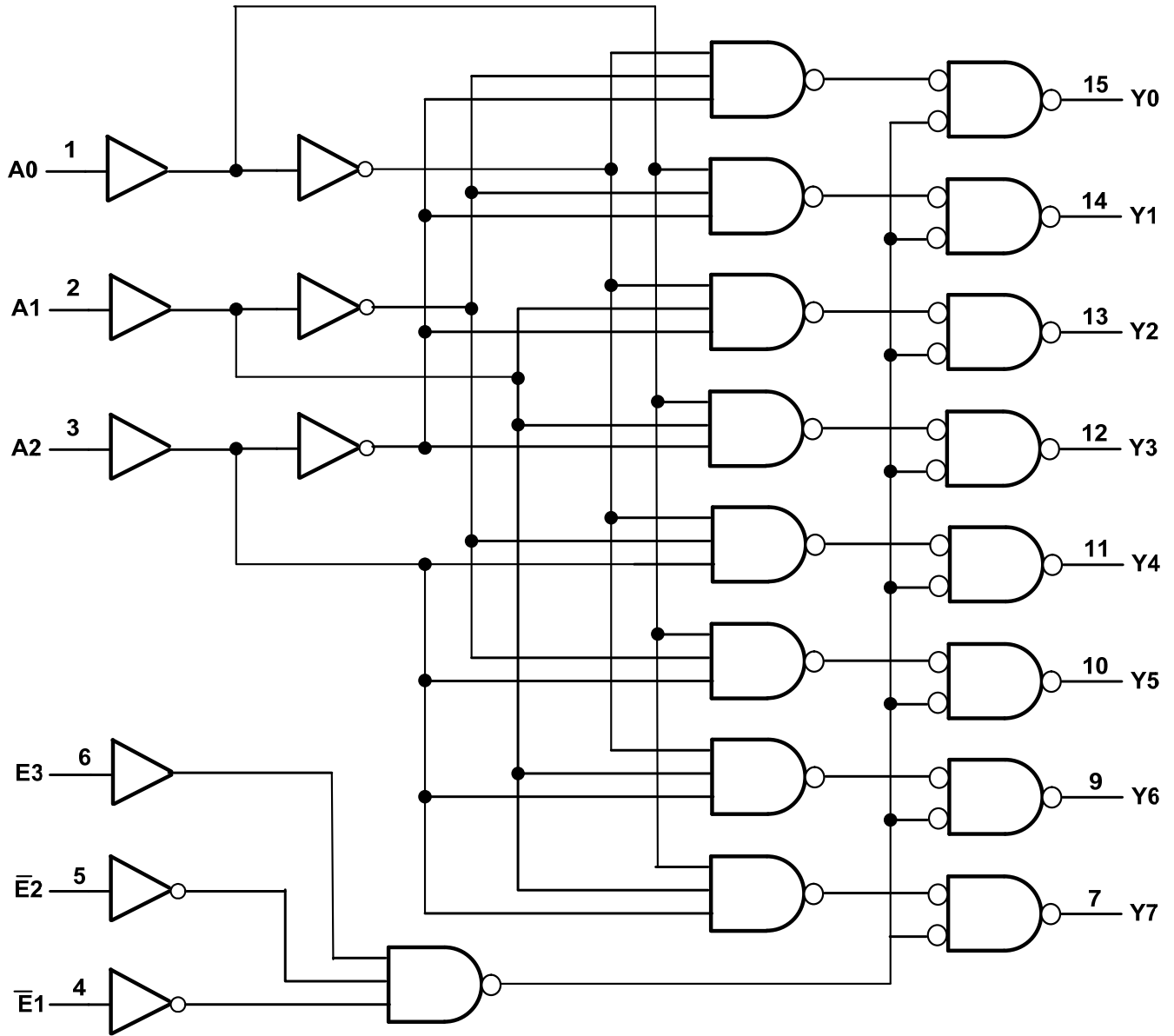
Pin Descriptions

Pin Number	Pin Name	Description
1	A0	Address Input 0
2	A1	Address Input 1
3	A2	Address Input 2
4	$\bar{E}1$	Enable Input 1 (active LOW)
5	$\bar{E}2$	Enable Input 2 (active LOW)
6	E3	Enable Input 3 (active HIGH)
7	Y7	Output 7 (active LOW)
8	GND	Ground
9	Y6	Output 6 (active LOW)
10	Y5	Output 5 (active LOW)
11	Y4	Output 4 (active LOW)
12	Y3	Output 3 (active LOW)
13	Y2	Output 2 (active LOW)
14	Y1	Output 1 (active LOW)
15	Y0	Output 0 (active LOW)
16	V _{CC}	Supply Voltage

Function Table Diagram

Control			Input			Output							
$\bar{E}1$	$\bar{E}2$	E3	A2	A1	A0	$\bar{Y}7$	$\bar{Y}6$	$\bar{Y}5$	$\bar{Y}4$	$\bar{Y}3$	$\bar{Y}2$	$\bar{Y}1$	$\bar{Y}0$
H	X	X	X	X	X	H	H	H	H	H	H	H	H
X	H	X											
X	X	L											
L	L	H											
			L	L	L	H	H	H	H	H	H	H	L
			L	L	H	H	H	H	H	H	H	L	H
			L	H	L	H	H	H	H	H	L	H	H
			L	H	H	H	H	H	H	L	H	H	H
			H	L	L	H	H	H	L	H	H	H	H
			H	L	H	H	H	L	H	H	H	H	H
			H	H	L	H	L	H	H	H	H	H	H
			H	H	H	L	H	H	H	H	H	H	H

Logic Diagram



Absolute Maximum Ratings (Note 4) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
V_I	Input Voltage Range	-0.5 to +7.0	V
V_O	Voltage applied to output in high or low state	-0.3 to $V_{CC} + 0.5$	V
I_{IK}	Input Clamp Current $V_I < -0.5\text{V}$	-20	mA
I_{OK}	Output Clamp Current $V_O < -0.5\text{V}$	-20	mA
I_{OK}	Output Clamp Current $V_O > V_{CC} + 0.5\text{V}$	25	mA
I_O	Continuous output current	+/- 25	mA
I_{CC}	Continuous current through V_{DD} or GND	75	mA
I_{GND}	Continuous current through V_{DD} or GND	-75	mA
T_J	Operating Junction Temperature	-40 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-65 to +150	$^\circ\text{C}$
P_{TOT}	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage		4.5	5.5	V
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	Active Mode	0	V_{CC}	V
$\Delta t/\Delta V$	Input transition Rise or Fall Rate	$V_{CC} = 4.5\text{V to } 5.5\text{V}$		20	ns/V
T_A	Operating Free-Air Temperature		-40	+125	$^\circ\text{C}$

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{CC}	$T_A = +25^\circ\text{C}$			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$		$T_A = -40^\circ\text{C to } +125^\circ\text{C}$		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V_{IH}	High-level Input Voltage		4.5V to 5.5V	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	Low-level input voltage		4.5V to 5.5V	-	-	0.8	-	0.8	-	0.8	V
V_{OH}	High Level Output Voltage	$I_{OH} = -50\mu\text{A}$	4.5V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{OH} = -8\text{mA}$	4.5V	3.94	-	-	3.80	-	3.70	-	V
V_{OL}	Low-level Output Voltage	$I_{OL} = 50\mu\text{A}$	4.5V	-	0	0.1	-	0.1	-	0.1	V
		$I_{OL} = 8\text{mA}$	4.5V	-	-	0.36	-	0.44	-	0.55	V
I_I	Input Current	$V_I = \text{GND or } 5.5\text{V}$	0V to 5.5V	-	0.1	± 0.1	-	± 1	-	± 2	μA
I_{CC}	Supply Current	$V_I = \text{GND or } V_{CC}$ $I_O = 0$	5.5V	-	-	4.0	-	40	-	80	μA
ΔI_{CC}	Additional Supply Current per Input	$V_I = V_{CC} - 2.1\text{V}$ $I_O = 0$	4.5V to 5.5V	-	-	1.35	-	1.5	-	1.5	mA
C_i	Input Capacitance	$V_I = V_{CC} \text{ or } \text{GND}$	5.5V	-	4	10	-	10	-	10	pF

Switching Characteristics

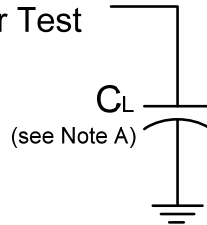
Symbol	Parameter	Test Conditions	V _{CC}	T _A = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t _{PD}	Propagation Delay An to Ȳn	Figure 2 C _L = 15pF	4.5V to 5.5V	0.5	4.4	10.4	1.0	12.0	1.0	13.0	ns
		Figure 2 C _L = 50pF	4.5V to 5.5V	0.5	6.2	11.4	1.0	13.0	1.0	14.5	
	Propagation Delay E3 to Ȳn	Figure 2 C _L = 15pF	4.5V to 5.5V	0.5	4.3	9.1	1.0	10.5	1.0	11.5	ns
		Figure 2 C _L = 50pF	4.5V to 5.5V	0.5	6.2	10.1	1.0	11.5	1.0	13.0	
	Propagation Delay Ēn to Ȳn	Figure 2 C _L = 15pF	4.5V to 5.5V	0.5	4.3	9.6	1.0	11.0	1.0	12.0	ns
		Figure 2 C _L = 50pF	4.5V to 5.5V	0.5	6.2	10.6	1.0	12.0	1.0	13.5	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

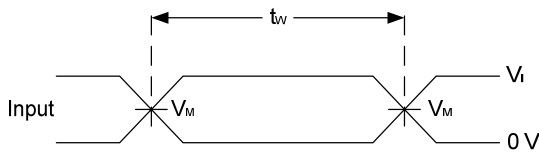
Parameter		Test Conditions	V _{CC} = 5V	Unit
			Typ	
C _{pd}	Power dissipation capacitance	f = 1 MHz all outputs switching-no load	23	pF

Parameter Measurement Information

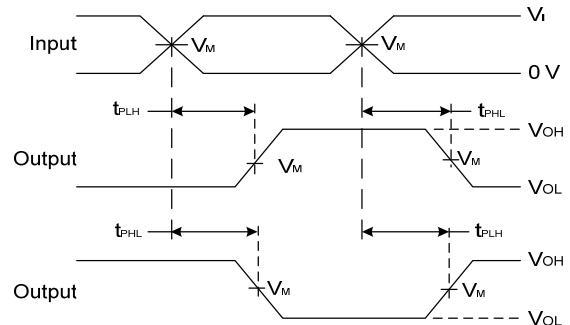
From Output Under Test



V _{CC}	Inputs		V _M		C _L
	V _I	t _r /t _f	Input	Output	
4.5V to 5.5V	3.0 V	3ns	1.5 V	V _{CC} /2	15pF, 50pF



**Voltage Waveform
Pulse Duration**

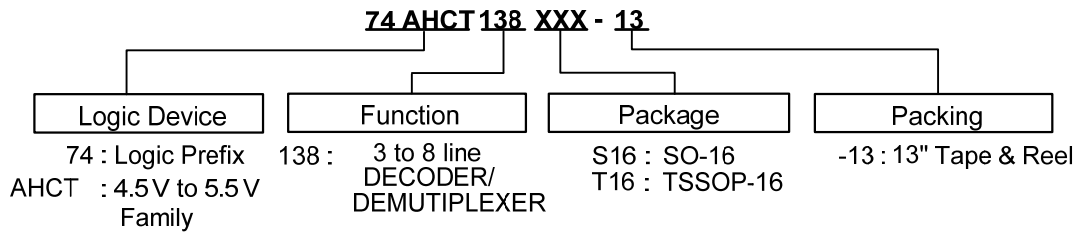


**Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs**

- Notes: A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}.

Figure 1. Load Circuit and Voltage Waveforms

Ordering Information

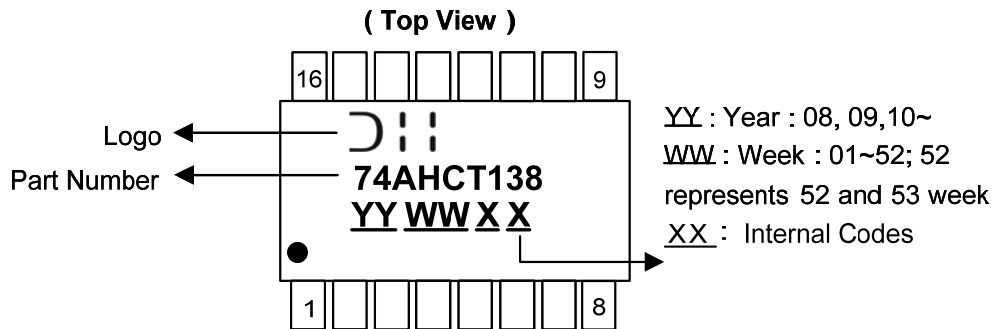


Part Number	Package Code	Packaging	7" Tape and Reel (Note 7)	
			Quantity	Part Number Suffix
74AHCT138S16-13	S16	SO-16	2500/Tape & Reel	-13
74AHCT138T16-13	T16	TSSOP-16	2500/Tape & Reel	-13

Notes: 7. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

Marking Information

(1) SO-16, TSSOP16

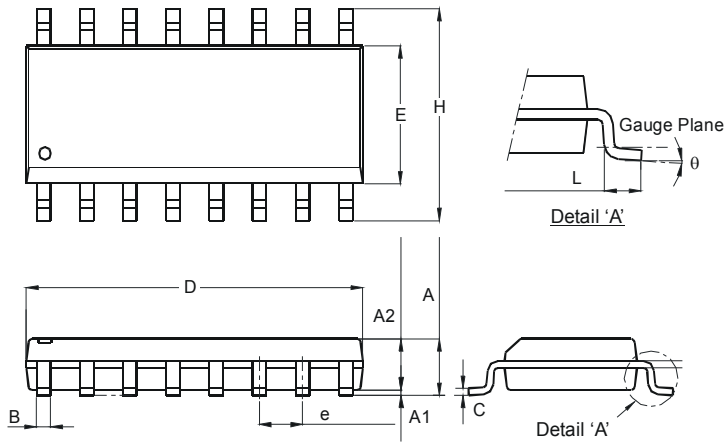


Part Number	Package
74AHCT138S16	SO-16
74AHCT138T16	TSSOP-16

Package Outline Dimensions (All dimensions in mm.)

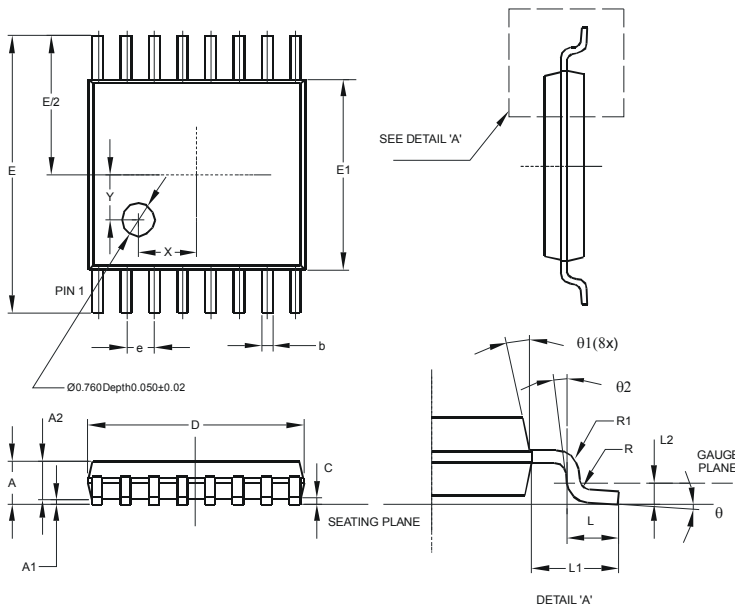
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

Package Type: SO-16



SO-16		
Dim	Min	Max
A	1.40	1.75
A1	0.10	0.25
A2	1.30	1.50
B	0.33	0.51
C	0.19	0.25
D	9.80	10.00
E	3.80	4.00
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-16

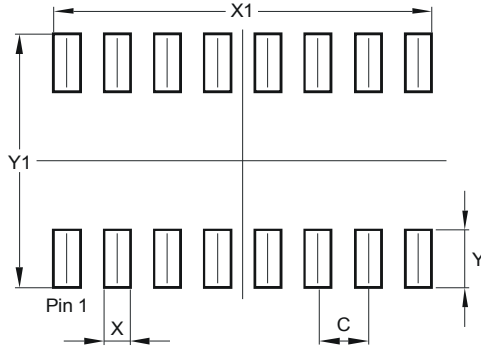


TSSOP-16			
Dim	Min	Max	Typ
A	-	1.08	-
A1	0.05	0.15	-
A2	0.80	0.93	-
b	0.19	0.30	-
c	0.09	0.20	-
D	4.90	5.10	-
E	6.40 BSC		
E1	4.30	4.50	-
e	0.65 BSC		
L	0.45	0.75	-
L1	1.00 REF		
L2	0.25 BSC		
R	0.09	-	-
R1	0.09	-	-
X	-	-	1.350
Y	-	-	1.050
θ	0°	8°	-
θ1	5°	15°	-
θ2	0°	-	-
All Dimensions in mm			

Suggested Pad Layout

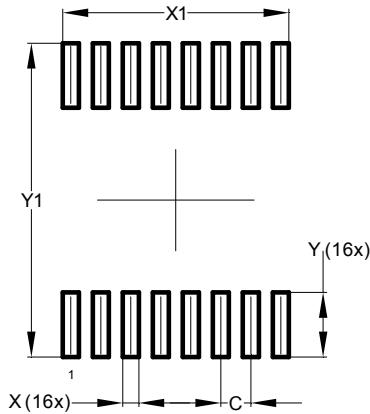
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
C	1.270
X	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
C	0.650
X	0.350
X1	4.900
Y	1.400
Y1	6.800

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